

1N56A
GOLD BONDED GERMANIUM DIODE

FEATURES

Low forward voltage drop—low power consumption
 Thirty years of proven reliability—one million hours mean time between failures (MTBF)
 Very low noise level
 Metallurgically bonded

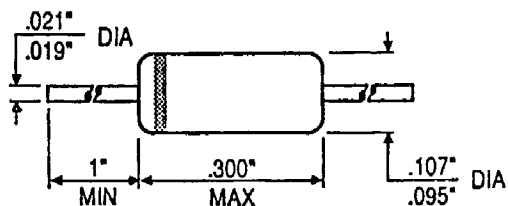
ABSOLUTE MAXIMUM RATINGS (at 25 °C, unless otherwise specified)

Peak Inverse Voltage	40 Volts
Peak Forward Current	500 mA
Operating Temperature Range	- 65 °C to 85 °C
Average Power Dissipation	80 mW

ELECTRICAL CHARACTERISTICS

	Symbol	Conditions	Min	Max	Unit	T °C
Peak Inverse Voltage	PIV	1 mA	40		V	25 °C
Reverse Current	I_r	30 V		300	μ A	25 °C
Forward Voltage	V_f	15 mA		1	V	25 °C

MECHANICAL



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

